

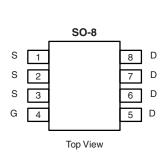
# F7820-VB Datasheet N-Channel 200-V (D-S) MOSFET

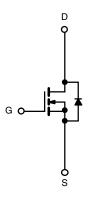
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
200	0.065 at V <sub>GS</sub> = 10 V	5.2		
	0.072 at V <sub>GS</sub> = 6.0 V	4.1		

#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- Trench Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC







N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unles	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		$V_{DS}$	200		V
Gate-Source Voltage		V <sub>GS</sub>	± 20		
Outlines Project Outline (T. 450.00)3	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	5.2	3.35	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		4.6	2.7	
Pulsed Drain Current		I <sub>DM</sub>	40		Α
Avalanch Current	L = 0.1 mH	I <sub>AS</sub>	15		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.6	1.3	
M	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.1	1.56	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	r D	2.0	1.0	VV
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55	to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
Martine Landing to Australia	t ≤ 10 s	- R <sub>thJA</sub>	33	40	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		65	80		
Maximum Junction-to-Foot (Drain)	Steady State	$R_{thJF}$	17	21		

Notes:
a. Surface Mounted on 1" x 1" FR4 board.

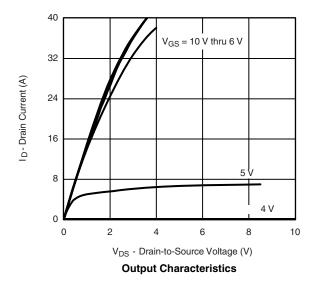


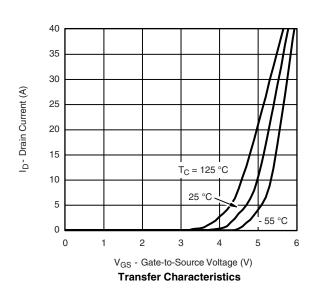
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtana Dunia Courset		V <sub>DS</sub> = 160 V, V <sub>GS</sub> = 0 V			1	μА	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5		
On-State Drain Current <sup>a</sup>		$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
	Б	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4.0 A		0.065			
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 6.0 \text{ V}, I_D = 4.0 \text{ A}$		0.072		Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 5 \text{ A}$		19		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 2.8 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.2	V	
Dynamic <sup>b</sup>				<b>'</b>			
Total Gate Charge	$Q_g$			34	42		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 4.0 \text{ A}$		7.5		nC	
Gate-Drain Charge	$Q_{gd}$			12.0			
Gate Resistance	$R_g$		0.2	0.85	1.3	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			14	20		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 100 V, $R_L$ = 25 $\Omega$		20	30	ŀ	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 4.0 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		32	50	ns	
Fall Time	t <sub>f</sub>			25	35		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.8 A, dI/dt = 100 A/μs		70	100		

- Notes: a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

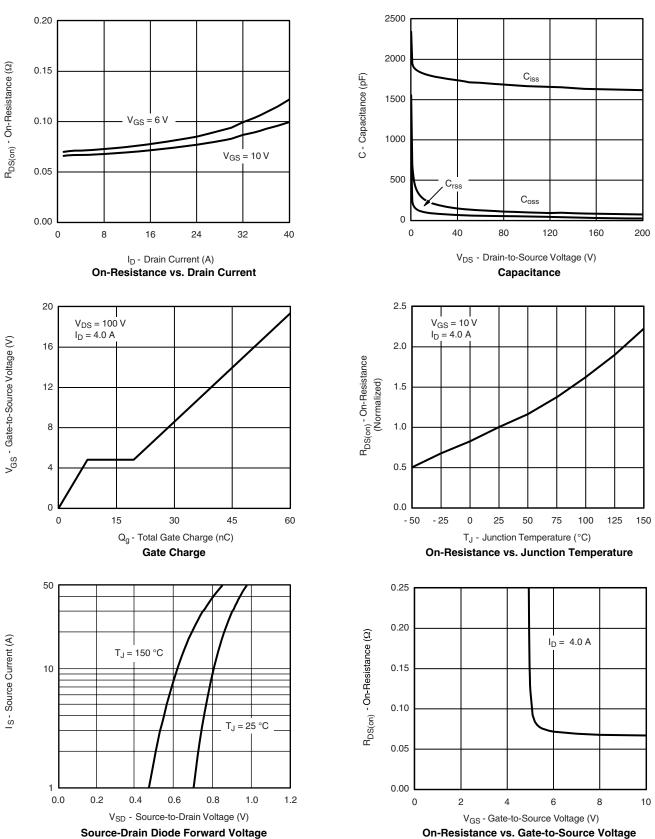
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





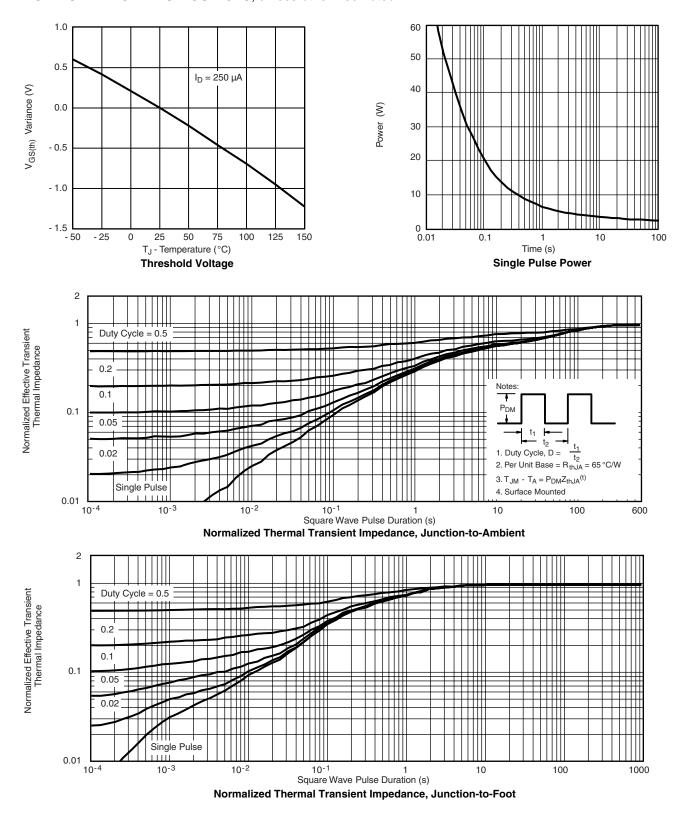


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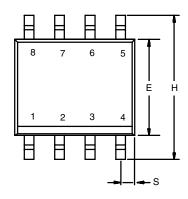


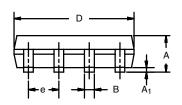
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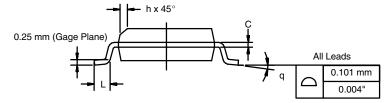




SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





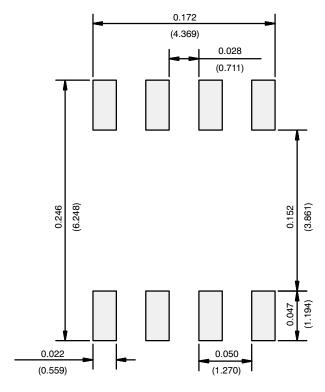


	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A <sub>1</sub>	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06						

DWG: 5498



### **RECOMMENDED MINIMUM PADS FOR SO-8**



Recommended Minimum Pads Dimensions in Inches/(mm)



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